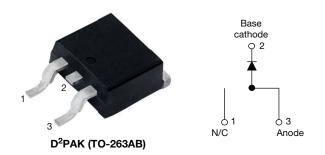
**Vishay Semiconductors** 

## High Performance Schottky Rectifier, 15 A



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PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	15 A			
V <sub>R</sub>	60 V			
V <sub>F</sub> at I <sub>F</sub>	0.56 V			
I <sub>RM</sub> max.	45 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
E <sub>AS</sub>	6 mJ			
Package	D <sup>2</sup> PAK (TO-263AB)			
Circuit configuration	Single			

### **FEATURES**

- 150 °C T<sub>J</sub> operation
- · Very low forward voltage drop
- High frequency operation



RoHS COMPLIANT HALOGEN

- High purity, high temperature epoxy FREE encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

The VS-15TQ060S-M3 Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I <sub>F(AV)</sub>	Rectangular waveform	15	А					
V <sub>RRM</sub>		60	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1000	А					
V <sub>F</sub>	15 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.56	V					
TJ	Range	-55 to +150	°C					

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-15TQ060S-M3 UNITS						
Maximum DC reverse voltage	V <sub>R</sub>	- 60	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	80	v			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 104 °C, rectangular waveform		15	A		
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse Following any rated   10 ms sine or 6 ms rect. pulse load condition and with rated V <sub>BBM</sub> applied		1000			
non-repetitive surge current See fig. 7	I <sub>FSM</sub>			260	A		
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.5 A, L = 11.5 mH		6	mJ		
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.50	A		

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		15 A	T.I = 25 °C	0.62	v		
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	30 A	$1_{\rm J} = 25$ C	0.82			
See fig. 1	VFM \''	15 A	15 A Τ <sub>1</sub> = 125 °C	0.56			
		30 A	1j=125 C	0.71			
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C		0.80	mA		
See fig. 2	IRM ()	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	45	ША		
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		720	pF		
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs		

Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and sto temperature range	orage	T <sub>J</sub> , T <sub>Stg</sub>		-55 to 150	°C	
Maximum thermal resistar junction to case	ice,	R <sub>thJC</sub>	DC operation See fig. 4	3.25	25 °C/W	
Typical thermal resistance case to heatsink	3	R <sub>thCS</sub>	Mounting surface, smooth, and greased	0.50	0/10	
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
Mounting torque	maximum			12 (10)	(lbf · in)	
Marking device			Case style D <sup>2</sup> PAK (TO-263AB)	15TQ	060S	

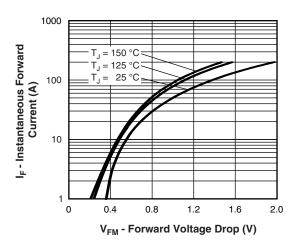


Fig. 1 - Maximum Forward Voltage Drop Characteristics

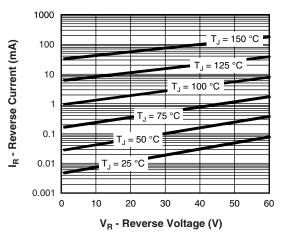
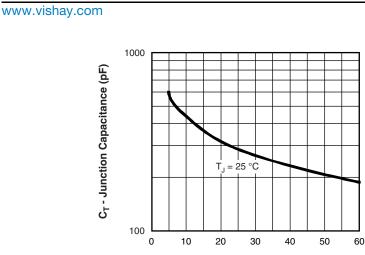


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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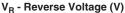
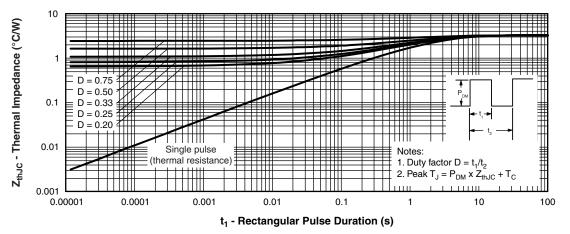
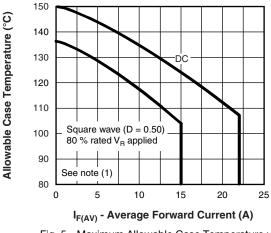
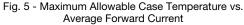


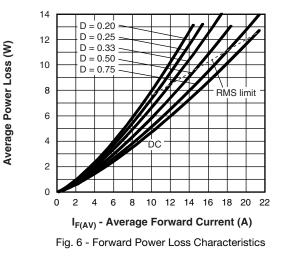
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage











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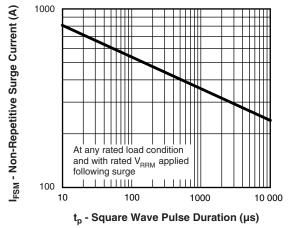


Fig. 7 - Maximum Non-Repetitive Surge Current

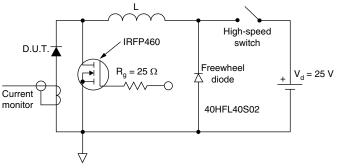
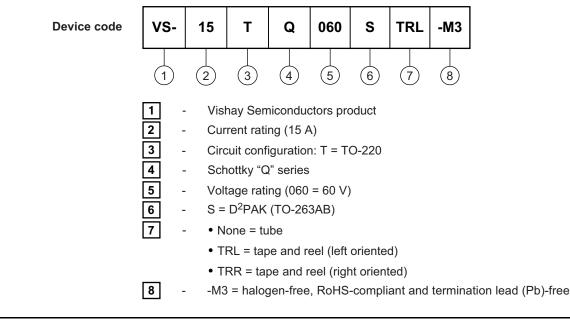


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

#### **ORDERING INFORMATION TABLE**



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# VS-15TQ060S-M3



### **Vishay Semiconductors**

ORDERING INFORMATION								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-15TQ060S-M3	50	1000	Antistatic plastic tubes					
VS-15TQ060STRR-M3	800	800	13" diameter reel					
VS-15TQ060STRL-M3	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96164			
Part marking information	www.vishay.com/doc?95444			
Packaging information	www.vishay.com/doc?96424			
SPICE model	www.vishay.com/doc?95600			

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D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INCHES		NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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